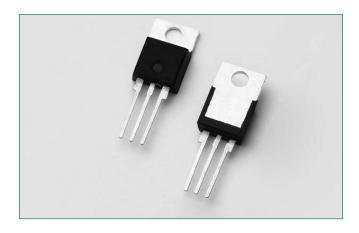


### SK225xD Series





#### **Description**

Excellent unidirectional switches for phase control applications such as heating and motor speed controls.

Standard phase control SCRs are triggered with few milliamperes of current at less than 1.5V potential.

#### **Features & Benefits**

- RoHS compliant
- Voltage capability up to 1200 V
- Surge capability up to 300 A

 Electrically isolated package "LD-Package" and UL Recognized for 2500V<sub>RMS</sub>

#### **Agency Recognitions**

Agency	Agency File Number
71.	E71639

#### **Applications**

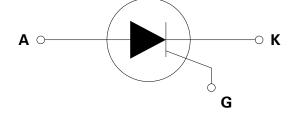
Typical applications are AC solid-state switches, industrial power tools, line rectification 50/60Hz.

Internally constructed isolated packages are offered for ease of heat sinking with highest isolation voltage.

#### **Main Features**

Symbol	Value	Unit
I <sub>T(RMS)</sub>	25	А
V <sub>DRM</sub> /V <sub>RRM</sub>	1200	V
l <sub>GT</sub>	40	mA

#### **Schematic Symbol**



# **Thyristors** 25 Amp Standard SCRs

#### Absolute Maximum Ratings — 25A SCR

Symbol	Parameter	Test Co	Test Conditions		Unit
$V_{DRM}/V_{RRM}$	Repetitive Peak off-state/Reverse Voltage				V
$V_{DSM}/V_{RSM}$	Non-repetitive peak off-state/Reverse voltage			1300	V
	RMS on-state current	SK225LD	T <sub>c</sub> =75°C	25	Α
T(RMS)	nivis ori-state current	SK225RD	T <sub>C</sub> =95°C	25	A
1	Average on state suggest	SK225LD	T <sub>c</sub> =75°C	16	^
I <sub>T(AV)</sub>	Average on-state current	SK225RD	T <sub>c</sub> =95°C	010	А
	Deal and a section of the section of	single half cycle; f = 50Hz; T <sub>J</sub> (initial) = 25°C		300	
I <sub>TSM</sub>	Peak non-repetitive surge current	single half cycle; $f = 6$ $T_J$ (initial) = 25°C	60Hz;	360	A
l²t	I²t Value for fusing	$t_p = 8.3 \text{ ms}$		540	A <sup>2</sup> s
di/dt	Critical rate of rise of on-state current			50	A/µs
I <sub>GM</sub>	Peak gate current	T <sub>J</sub> = 125°C		3	А
P <sub>G(AV)</sub>	Average gate power dissipation	T <sub>J</sub> = 125°C		1	W
T <sub>stg</sub>	Storage temperature range			-40 to 150	°C
T	Operating junction temperature range			-40 to 125	°C

Notes : x = package

## Electrical Characteristics (T<sub>J</sub> = 25°C, unless otherwise specified)

Symbol	Test Conditions	Value	Unit	
I <sub>GT</sub>	V 12V. D 200	MAX.	40	mA
V <sub>GT</sub>	$V_D = 12V; R_L = 30\Omega$	MAX.	1.5	V
dv/dt	$V_D = 2/3 V_{DRM}$ ; gate open; $T_J = 125$ °C	MIN.	1000	V/µs
V <sub>GD</sub>	$V_{D} = V_{DRM}$ ; $R_{L} = 3.3 \text{ k}\Omega$ ; $T_{J} = 125^{\circ}\text{C}$	MIN.	0.2	V
I <sub>H</sub>	$I_{T} = 500 \text{mA (initial)}$	MAX.	100	mA
t <sub>q</sub>	$I_T=0.5A$ ; $t_p=50\mu s$ ; $dv/dt=5V/\mu s$ ; $di/dt=-30A/\mu s$	TYP.	15	μs
t <sub>ot</sub>	$I_{G} = 2 \times I_{GT}$ ; PW = 15 $\mu$ s; $I_{T} = 50$ A	TYP.	3	μs

Notes : x = package

#### **Static Characteristics**

Symbol	Test Conditions			Value	Unit
$V_{TM}$	$I_{T} = 50A; t_{p} = 380 \mu s$		MAX.	1.6	V
1 /1	V (V	T <sub>J</sub> = 25°C	NAAV	10	μΑ
I <sub>DRM</sub> / I <sub>RRM</sub>	$V_{DRM}/V_{RRM}$	T <sub>J</sub> = 125°C	MAX.	4	mA

#### **Thermal Resistances**

Symbol	Parameter	Value	Unit	
D. Hungstian to appoint (AC)		SK225RD	1.0	°C/W
$R_{\Theta(JC)}$	Junction to case (AC)	SK225LD	1.9	



Figure 1: Normalized DC Gate Trigger Current vs. Junction Temperature

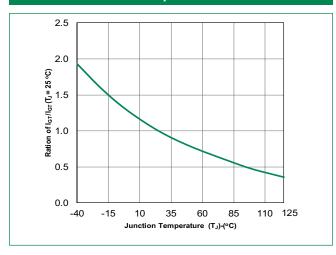


Figure 3: Normalized DC Holding Current vs. Junction Temperature

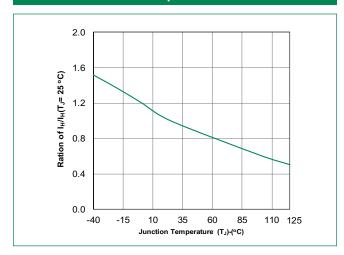


Figure 5: Power Dissipation (Typical) vs. RMS On-State Current

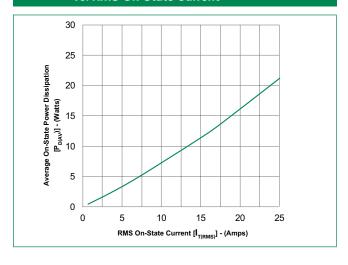


Figure 2: Normalized DC Gate Trigger Voltage vs. Junction Temperature

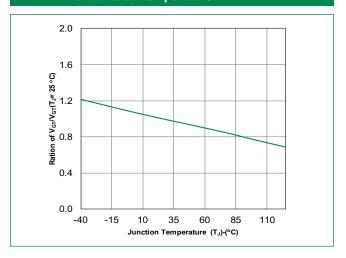


Figure 4: On-State Current vs. On-State Voltage (Typical)

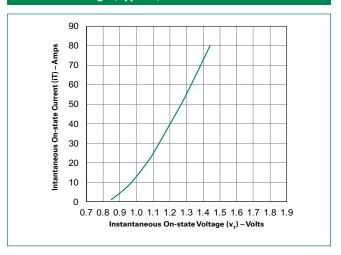


Figure 6: Maximum Allowable Case Temperature vs. RMS On-State Current

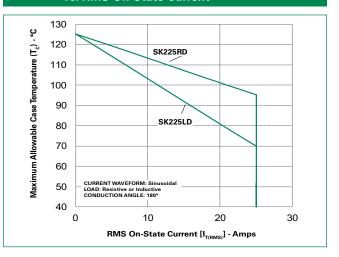




Figure 7: Maximum Allowable Case Temperature vs. Average On-State Current

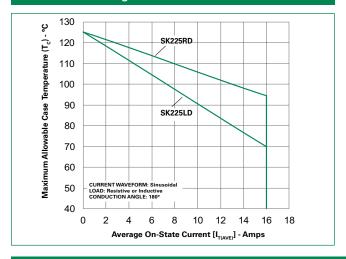


Figure 8: Surge Peak On-State Current vs. Number of Cycles



SUPPLY FREQUENCY: 50 Hz Sinusoidal LOAD: Resistive

RMS On-State Current:  $[I_{T(RMS)}]$ : Maximum Rated Value at Specified Case Temperature

#### Notes:

- 1. Gate control may be lost during and immediately following surge current interval.
- 2. Overload may not be repeated until junction temperature has returned to steady-state rated value.

#### **Environmental Specifications**

Test	Specifications and Conditions
AC Blocking	JESD22-A108C, 80% V <sub>DRM</sub> @125°C for 168 hours
Temperature Cycling	MIL-STD-750, M-1051, 100 cycles; -40°C to +150°C; 15-min dwell-time
Temperature/Humidity	EIA / JEDEC, JESD22-A101 168 hours; 100V - DC: 85°C; 85% rel humidity
Resistance to Solder Heat	JESD22-B106C
Solderability	J-STD-022, category 3, test A

#### **Physical Specification**

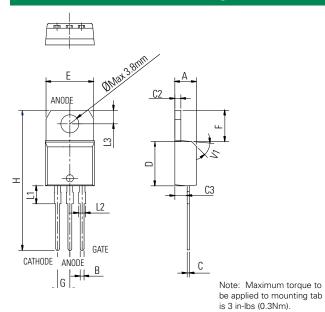
Terminal Finish	100% Matte Tin-Plated		
Body Material	UL Recognized compound meeting flammability rating V-0		

#### **Design Considerations**

Careful selection of the correct component for the application's operating parameters and environment will go a long way toward extending the operating life of the Thyristor. Good design practice should limit the maximum continuous current through the main terminals to 75% of the component rating. Other ways to ensure long life for a power discrete semiconductor are proper heat sinking and selection of voltage ratings for worst case conditions. Overheating, overvoltage (including dv/dt), and surge currents are the main killers of semiconductors. Correct mounting, soldering, and forming of the leads also help protect against component damage.

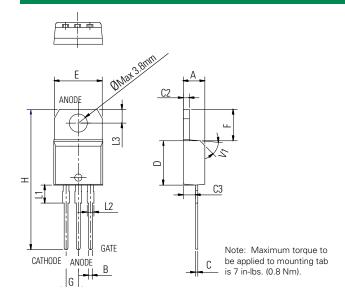


#### Dimensions — TO-220AB (RD-Package) — Non-Isolated Mounting Tab Common with Center Lead



Dimension	Millimeters			Inches		
Difficusion	Min.	Тур.	Max.	Min.	Тур.	Max.
Α	4.40		4.60	0.173		0.181
В	0.61		0.88	0.024		0.035
С	0.46		0.70	0.018		0.028
C2	1.21		1.32	0.048		0.052
C3	2.40		2.72	0.094		0.107
D	8.60		9.70	0.339		0.382
E	9.60		10.4	0.378		0.409
F	6.20		6.60	0.244		0.260
G		2.54			0.1	
Н	28.0		29.8	1.102		1.173
L1		3.75			0.148	
L2	1.14		1.70	0.045		0.067
L3	2.65		2.95	0.104		0.116
V1		45°			45°	

#### Dimensions — TO-220AB (LD-Package) — Isolated Mounting Tab

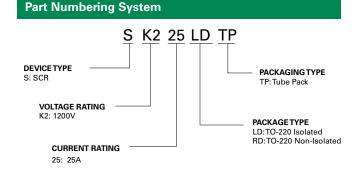


D:	ı	Millimeters			Inches		
Dimension	Min.	Тур.	Max.	Min.	Тур.	Max.	
Α	4.40		4.60	0.173		0.181	
В	0.61		0.88	0.024		0.035	
С	0.46		0.70	0.018		0.028	
C2	1.21		1.32	0.048		0.052	
C3	2.40		2.72	0.094		0.107	
D	8.60		9.70	0.339		0.382	
E	9.80		10.4	0.386		0.409	
F	6.55		6.95	0.258		0.274	
G		2.54			0.1		
Н	28.0		29.8	1.102		1.173	
L1		3.75			0.148		
L2	1.14		1.70	0.045		0.067	
L3	2.65		2.95	0.104		0.116	
V1		45°			45°		

## **Thyristors**25 Amp Standard SCRs

# Part Number Gate Sensitivity Type Package SK225LD 40mA Standard SCR TO-220L SK225RD 40mA Standard SCR TO-220R

Packing Options				
Part Number	Marking	Weight	Packing Mode	Base Quantity
SK225LDTP	SK225LD	2.2g	Tube	1000
SK225RDTP	SK225RD	2.0g	Tube	1000



#### **Part Marking System**



XXX: Lot Trace Code